Designer's™ Data Sheet

Insulated Gate Bipolar Transistor with Anti-Parallel Diode N-Channel Enhancement-Mode Silicon Gate

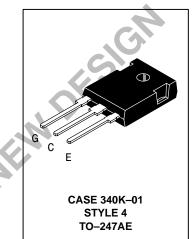
This Insulated Gate Bipolar Transistor (IGBT) is co-packaged with a soft recovery ultra-fast rectifier and uses an advanced termination scheme to provide an enhanced and reliable high voltage-blocking capability. Short circuit rated IGBT's are specifically suited for applications requiring a guaranteed short circuit withstand time such as Motor Control Drives. Fast switching characteristics result in efficient operation at high frequencies. Co-packaged IGBT's save space, reduce assembly time and cost.

- Industry Standard High Power TO–247 Package with Isolated Mounting Hole
- High Speed E_{off}: 150 μJ/A typical at 125°C
- High Short Circuit Capability 10 μs minimum
- Soft Recovery Free Wheeling Diode is included in the package
- Robust High Voltage Termination
- Robust RBSOA



Motorola Preferred Device

IGBT & DIODE IN TO-247 12 A @ 90°C 20 A @ 25°C 1200 VOLTS SHORT CIRCUIT RATED



Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CES}	1200	Vdc
Collector–Gate Voltage (R_{GE} = 1.0 M Ω)	V _{CGR}	1200	Vdc
Gate-Emitter Voltage — Continuous	V _{GE}	±20	Vdc
Collector Current— Continuous @ $T_C = 25^{\circ}C$ — Continuous @ $T_C = 90^{\circ}C$ — Repetitive Pulsed Current (1)	I _{C25} I _{C90} I _{CM}	20 12 40	Adc Apk
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	125 0.98	Watts W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to 150	°C
Short Circuit Withstand Time (V_{CC} = 720 Vdc, V_{GE} = 15 Vdc, T_J = 125°C, R_G = 20 Ω)	t _{sc}	10	μs
Thermal Resistance — Junction to Case – IGBT — Junction to Case – Diode — Junction to Ambient	R _{θJC} R _{θJC} R _{θJA}	1.0 1.4 45	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	TL	260	°C
Mounting Torque, 6-32 or M3 screw	10 lbf•in (1.13 N•m)		

MAXIMUM RATINGS (T_{.1} = 25°C unless otherwise noted)

(1) Pulse width is limited by maximum junction temperature. Repetitive rating.

Designer's Data for "Worst Case" Conditions — The Designer's Data Sheet permits the design of most circuits entirely from the information presented. SOA Limit curves — representing boundaries on device characteristics — are given to facilitate "worst case" design.

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Preferred devices are Motorola recommended choices for future use and best overall value.

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MGW12N120D

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Ch	aracteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector-to-Emitter Breakdown	/oltage	V _{(BR)CES}				Vdc
$(V_{GE} = 0 \text{ Vdc}, I_C = 25 \mu \text{Adc})$ Temperature Coefficient (Positiv	ve)		1200		_	mV/∘C
Zero Gate Voltage Collector Curre		I _{CES}		0.0		μAdc
$(V_{CE} = 1200 \text{ Vdc}, V_{GE} = 0 \text{ Vdc})$		ICES	_	_	100	μλασ
$(V_{CE} = 1200 \text{ Vdc}, V_{GE} = 0 \text{ Vdc},$	$T_{J} = 125^{\circ}C)$		—	—	2500	
Gate-Body Leakage Current (VGB	$t = \pm 20$ Vdc, V _{CE} = 0 Vdc)	I _{GES}	—	_	250	nAdc
ON CHARACTERISTICS (1)			0			
Collector-to-Emitter On-State Vo	Itage	V _{CE(on)}		2.71	2 27	Vdc
(V _{GE} = 15 Vdc, I _C = 5.0 Adc) (V _{GE} = 15 Vdc, I _C = 5.0 Adc, T _J	= 125°C)		_	3.78	3.37	
$(V_{GE} = 15 \text{ Vdc}, I_C = 10 \text{ Adc})$				3.5	4.42	
Gate Threshold Voltage		V _{GE(th)}	4.0			Vdc
$(V_{CE} = V_{GE}, I_C = 1.0 \text{ mAdc})$ Threshold Temperature Coeffici	ent (Negative)		4.0	6.0 10	8.0	mV/°C
Forward Transconductance (V _{CE}		9 _{fe}		12	_	Mhos
		Jie				
Input Capacitance		C _{ies}		1003		pF
Output Capacitance	$(V_{CE} = 25 \text{ Vdc}, V_{GE} = 0 \text{ Vdc},$	C _{oes}		126		
Transfer Capacitance	f = 1.0 MHz)	C _{res}		106		-
SWITCHING CHARACTERISTICS	(1)	103				
Turn–On Delay Time	Ť	t _{d(on)}	_	74	_	ns
Rise Time		t _r	_	83	_	-
Turn–Off Delay Time	(V _{CC} = 720 Vdc, I _C = 10 Adc,	t _{d(off)}		76		
Fall Time	V _{GE} = 15 Vdc, L = 300 μH	t _f		231		-
Turn–Off Switching Loss	$R_{G} = 20 \Omega$) Energy losses include "tail"	E _{off}	_	0.55	1.33	mJ
Turn–On Switching Loss		E _{on}		1.21	1.88	-
Total Switching Loss		E _{ts}	_	1.76	3.21	
Turn–On Delay Time		t _{d(on)}		66		ns
Rise Time	-	t _r		87		
Turn–Off Delay Time				120		
Fall Time	(V _{CC} = 720 Vdc, I _C = 10 Adc, V _{GE} = 15 Vdc, L = 300 μH	t _{d(off)}		575		-
Turn–Off Switching Loss	$R_{G} = 20 \Omega, T_{J} = 125^{\circ}C)$	t _f				
Turn–On Switching Loss	Energy losses include "tail"	E _{off}	—	1.49		mJ
ŭ		E _{on}	—	2.37		
Total Switching Loss	·	E _{ts}	—	3.86		
Gate Charge	(V _{CC} = 720 Vdc, I _C = 10 Adc,	Q _T	—	29		nC
	$V_{GE} = 15$ Vdc)	Q ₁	—	13		
		Q ₂	—	12		
DIODE CHARACTERISTICS						
Diode Forward Voltage Drop (I _{EC} = 5.0 Adc)		V _{FEC}	_	2.26	3.32	Vdc
$(I_{EC} = 5.0 \text{ Adc}, T_{J} = 125^{\circ}\text{C})$			—	1.37	—	
(I _{EC} = 10 Adc)			—	2.86	4.18	

(1) Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%.

(continued)

ELECTRICAL CHARACTERISTICS - continued (T_J = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
DIODE CHARACTERISTICS — conti	nued	·				
Reverse Recovery Time		t _{rr}	—	116	—	ns
	(I _F = 10 Adc, V _R = 720 Vdc, dI _F /dt = 100 A/μs)	ta	—	69	-	
		t _b	—	47	—	
Reverse Recovery Stored Charge		Q _{RR}	—	0.36	—	μC
Reverse Recovery Time	(I _F = 10 Adc, V _R = 720 Vdc, dI _F /dt = 100 A/µs, T _J = 125°C)	t _{rr}	—	234	—	ns
		ta	—	149	—	
		t _b	—	85	_	
Reverse Recovery Stored Charge		Q _{RR}	—	1.40	_	μC
NTERNAL PACKAGE INDUCTANCE						
Internal Emitter Inductance (Measured from the emitter lead 0.	25" from package to emitter bond pad)	LE	_	13	CT.	nH
	TYPICAL ELECTRICAL CHAR	ACTERISTIC	s	.0		•



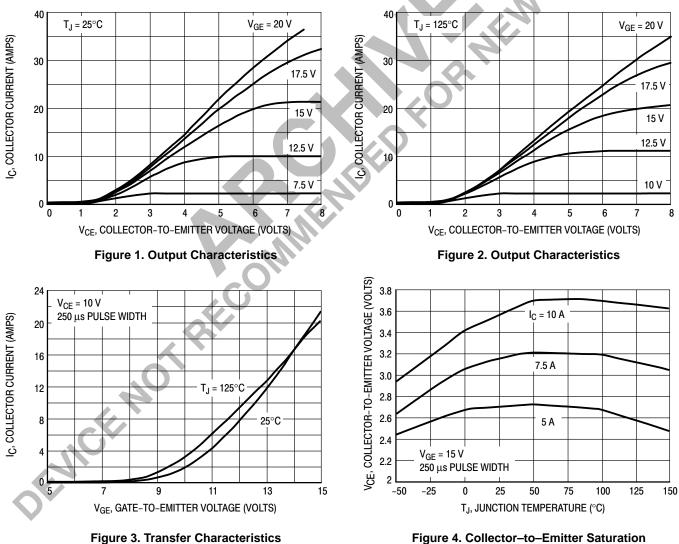
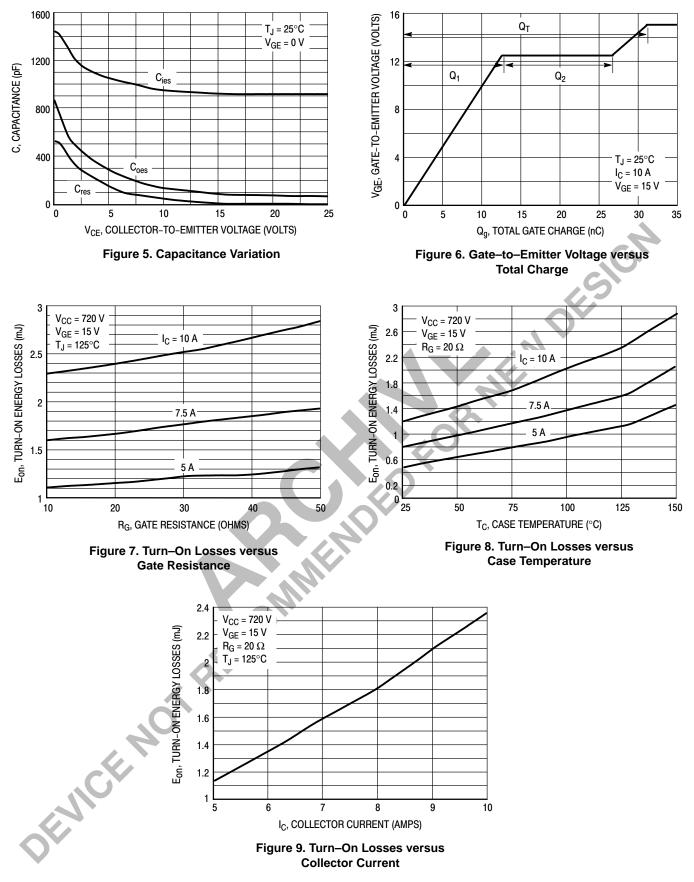
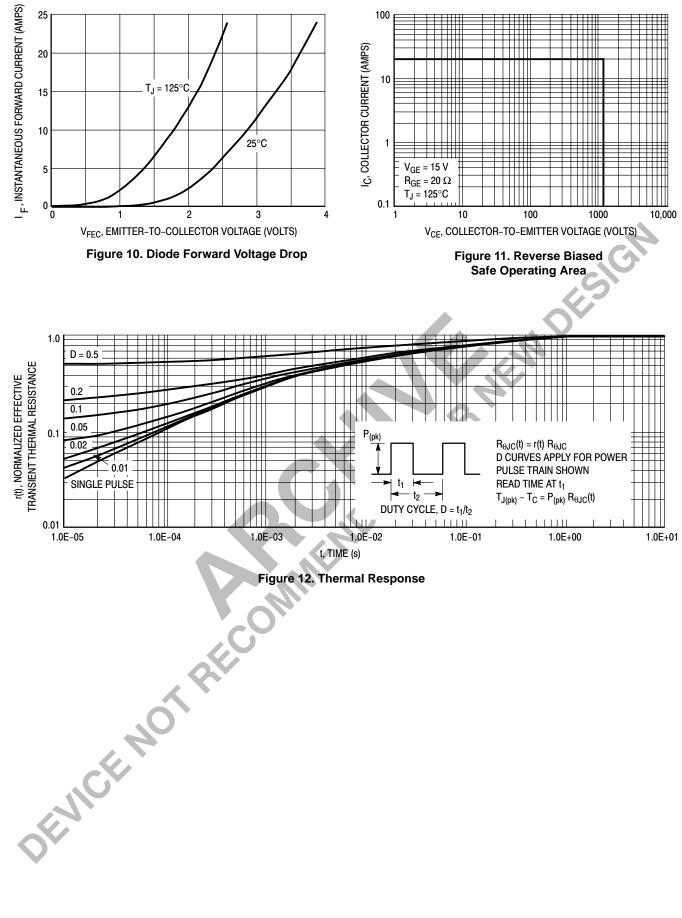


Figure 4. Collector-to-Emitter Saturation Voltage versus Junction Temperature

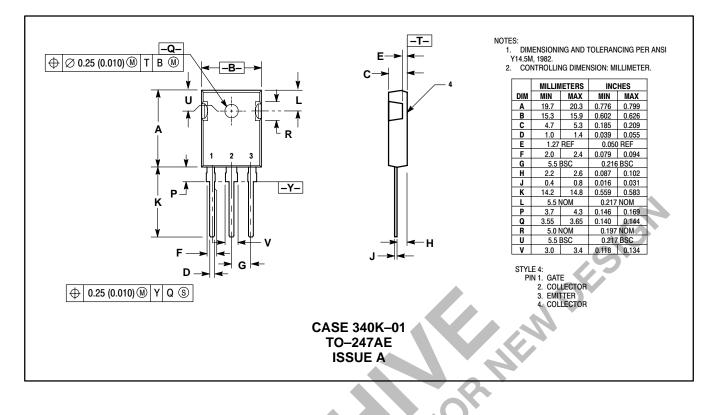
MGW12N120D



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PACKAGE DIMENSIONS



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